TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC74AC02P, TC74AC02F, TC74AC02FT

#### Quad 2-Input NOR Gate

The TC74AC02 is an advanced high speed CMOS 2-INPUT NOR GATE fabricated with silicon gate and double-layer metal wiring  $C^2$ MOS technology.

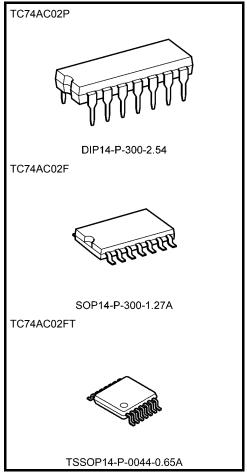
It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The internal circuit is composed of 3 stages including buffer output, which provide high noise immunity and stable output.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

#### **Features**

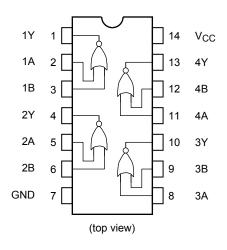
- High speed:  $t_{pd} = 3.7 \text{ ns}$  (typ.) at  $V_{CC} = 5 \text{ V}$
- Low power dissipation:  $I_{CC} = 4 \mu A \text{ (max)}$  at  $T_a = 25 \text{°C}$
- High noise immunity: V<sub>NIH</sub> = V<sub>NIL</sub> = 28% V<sub>CC</sub> (min)
- Symmetrical output impedance:  $|I_{OH}| = I_{OL} = 24$  mA (min) Capability of driving 50  $\Omega$  transmission lines.
- Balanced propagation delays:  $t_{pLH} \simeq t_{pHL}$
- Wide operating voltage range:  $V_{CC \text{ (opr)}} = 2 \text{ to } 5.5 \text{ V}$
- Pin and function compatible with 74F02



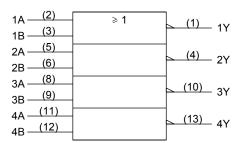
Weight

DIP14-P-300-2.54 : 0.96 g (typ.) SOP14-P-300-1.27A : 0.18 g (typ.) TSSOP14-P-0044-0.65A : 0.06 g (typ.)

#### **Pin Assignment**



#### **IEC Logic Symbol**



#### **Truth Table**

| Α | В | Υ |
|---|---|---|
| L | L | Н |
| L | Н | L |
| Н | L | L |
| Н | Н | L |

### **Absolute Maximum Ratings (Note 1)**

| Characteristics                    | Symbol           | Rating                             | Unit |
|------------------------------------|------------------|------------------------------------|------|
| Supply voltage range               | V <sub>CC</sub>  | −0.5 to 7.0                        | V    |
| DC input voltage                   | V <sub>IN</sub>  | -0.5 to V <sub>CC</sub> + 0.5      | V    |
| DC output voltage                  | V <sub>OUT</sub> | -0.5 to V <sub>CC</sub> + 0.5      | V    |
| Input diode current                | I <sub>IK</sub>  | ±20                                | mA   |
| Output diode current               | lok              | ±50                                | mA   |
| DC output current                  | lout             | ±50                                | mA   |
| DC V <sub>CC</sub> /ground current | Icc              | ±100                               | mA   |
| Power dissipation                  | PD               | 500 (DIP) (Note 2)/180 (SOP/TSSOP) | mW   |
| Storage temperature                | T <sub>stg</sub> | −65 to 150                         | °C   |

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: 500 mW in the range of Ta = -40 to 65°C. From Ta = 65 to 85°C a derating factor of -10 mW/°C should be applied up to 300 mW.



### **Operating Ranges (Note)**

| Characteristics          | Symbol           | Rating                                       | Unit   |  |
|--------------------------|------------------|--|--------|--|
| Supply voltage           | V <sub>CC</sub>  | 2.0 to 5.5                                   | V      |  |
| Input voltage            | V <sub>IN</sub>  | 0 to V <sub>CC</sub>                         | V      |  |
| Output voltage           | V <sub>OUT</sub> | 0 to V <sub>CC</sub>                         | V      |  |
| Operating temperature    | T <sub>opr</sub> | −40 to 85                                    | °C     |  |
| Input rise and fall time | dt/dV            | 0 to 100 (V <sub>CC</sub> = $3.3 \pm 0.3$ V) | ns/V   |  |
| input rise and rail time | avav             | 0 to 20 ( $V_{CC} = 5 \pm 0.5 \text{ V}$ )   | 115/ V |  |

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either  $V_{CC}$  or GND.

#### **Electrical Characteristics**

#### **DC Characteristics**

| Characteristics Symbol       | Symbol          | Test Condition                           |                           |                        | Ta = 25°C |      | Ta =<br>-40 to 85°C |      | Unit |       |     |
|------------------------------|-----------------|--|---------------------------|------------------------|-----------|------|---------------------|------|------|-------|-----|
|                              |                 |  |                           | V <sub>CC</sub><br>(V) | Min       | Тур. | Max                 | Min  | Max  | Offic |     |
|                              |                 |  |                           |                        | 2.0       | 1.50 | _                   | _    | 1.50 | _     |     |
| High-level input voltage     | V <sub>IH</sub> | _  |                           |                        | 3.0       | 2.10 | _                   | _    | 2.10 | _     | V   |
|                              |                 |  |                           |                        | 5.5       | 3.85 | _                   | _    | 3.85 | _     |     |
|                              |                 |  |                           |                        | 2.0       | _    | _                   | 0.50 | _    | 0.50  |     |
| Low-level input voltage      | $V_{IL}$        |  | _                         |                        | 3.0       | _    | _                   | 0.90 | _    | 0.90  | V   |
|                              |                 |  |                           |                        | 5.5       | _    | _                   | 1.65 | _    | 1.65  |     |
|                              |                 | V <sub>IN</sub><br>= V <sub>IL</sub>     |                           |                        | 2.0       | 1.9  | 2.0                 | _    | 1.9  | _     |     |
|                              |                 |  | I <sub>OH</sub> = -50 μA  | 3.0                    | 2.9       | 3.0  | _                   | 2.9  | _    | V     |     |
| High-level output            | VoH             |  |                           |                        | 4.5       | 4.4  | 4.5                 | _    | 4.4  |       | _   |
| voltage                      | ▼On             |  | $I_{OH} = -4 \text{ mA}$  |                        | 3.0       | 2.58 | _                   | _    | 2.48 | _     | V   |
|                              |                 |  | I <sub>OH</sub> = -24 mA  |                        | 4.5       | 3.94 | _                   | _    | 3.80 | _     |     |
|                              |                 |  | $I_{OH} = -75 \text{ mA}$ | (Note)                 | 5.5       | _    | _                   | _    | 3.85 | _     |     |
|                              |                 |  |                           |                        | 2.0       | _    | 0.0                 | 0.1  | _    | 0.1   |     |
|                              |                 |  | I <sub>OL</sub> = 50 μA   | 3.0                    | _         | 0.0  | 0.1                 | _    | 0.1  | V     |     |
| Low-level output voltage Vol | Voi             | V <sub>IN</sub><br>= V <sub>IH</sub> or  |                           |                        | 4.5       | _    | 0.0                 | 0.1  | _    |       | 0.1 |
|                              | *OL             | VIL                                      | I <sub>OL</sub> = 12 mA   |                        | 3.0       | _    | _                   | 0.36 | _    | 0.44  |     |
|                              |                 |  | I <sub>OL</sub> = 24 mA   |                        | 4.5       | _    | _                   | 0.36 | _    | 0.44  |     |
|                              |                 |  | $I_{OL} = 75 \text{ mA}$  | (Note)                 | 5.5       | _    | _                   | _    | _    | 1.65  |     |
| Input leakage current        | I <sub>IN</sub> | $V_{IN} = V_{CC}$ or GND                 |                           |                        | 5.5       | ı    | ı                   | ±0.1 | _    | ±1.0  | μΑ  |
| Quiescent supply current     | Icc             | V <sub>IN</sub> = V <sub>CC</sub> or GND |                           |                        | 5.5       | _    | _                   | 4.0  | _    | 40.0  | μA  |

3

Note: This spec indicates the capability of driving 50  $\Omega$  transmission lines. One output should be tested at a time for a 10 ms maximum duration.



## AC Characteristics (CL = 50 pF, RL = 500 $\Omega,$ input: $t_r$ = $t_f$ = 3 ns)

| Characteristics Symbol           | Symbol           | Test Condition |                     | Ta = 25°C |      |     | Ta =<br>-40 to 85°C |      | Unit |
|----------------------------------|------------------|----------------|---------------------|-----------|------|-----|---------------------|------|------|
|                                  | ,                |                | V <sub>CC</sub> (V) | Min       | Тур. | Max | Min                 | Max  |      |
| Propagation delay tpLH time tpHL | t <sub>pLH</sub> |                | $3.3\pm0.3$         | _         | 6.1  | 9.8 | 1.0                 | 11.2 | 20   |
|                                  | t <sub>pHL</sub> | _              | $5.0\pm0.5$         | _         | 4.8  | 7.0 | 1.0                 | 8.0  | ns   |
| Input capacitance                | C <sub>IN</sub>  | _              |                     | _         | 5    | 10  | _                   | 10   | pF   |
| Power dissipation capacitance    | C <sub>PD</sub>  |                | (Note)              | _         | 82   | ı   | _                   | _    | pF   |

Note: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

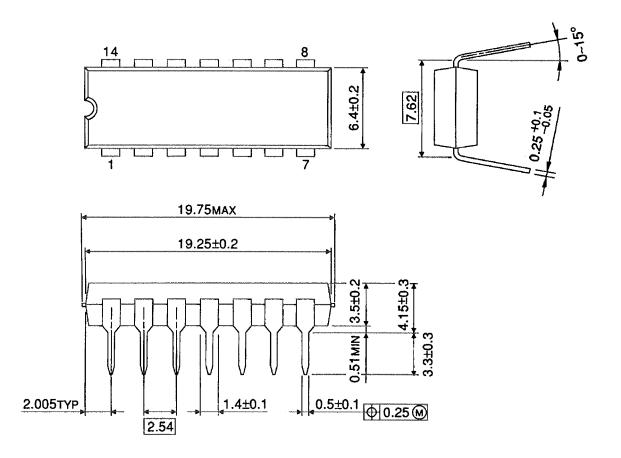
Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/4 \text{ (per gate)}$ 



## **Package Dimensions**

DIP14-P-300-2.54 Unit: mm

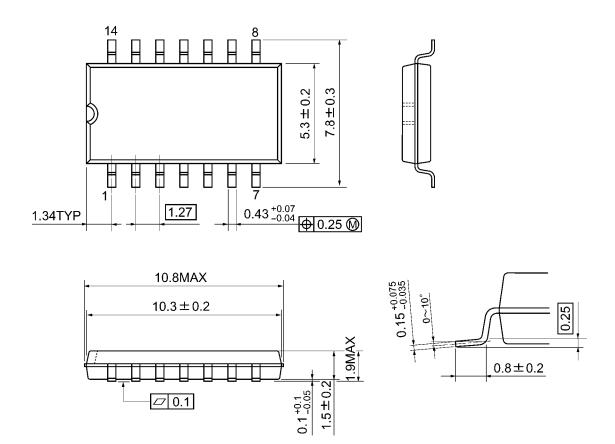


Weight: 0.96 g (typ.)



### **Package Dimensions**

SOP14-P-300-1.27A Unit: mm



6

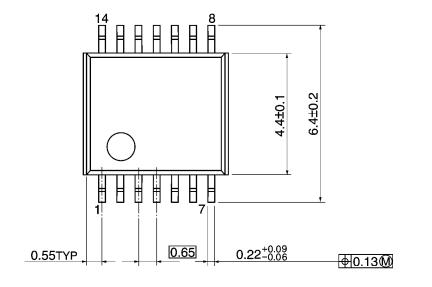
Weight: 0.18 g (typ.)

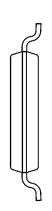


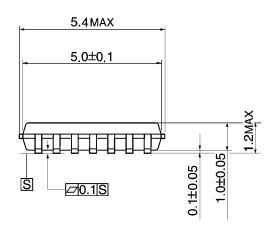
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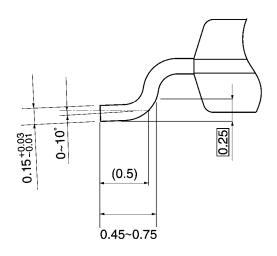
TSSOP14-P-0044-0.65A

Unit: mm









Weight: 0.06 g (typ.)

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